

Gate-Reflectometry Dispersive Readout of a Spin Qubit in Silicon

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arXiv:1811.04414v1

- FAM talk -

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Scalability

Measurement

Quantum Gates

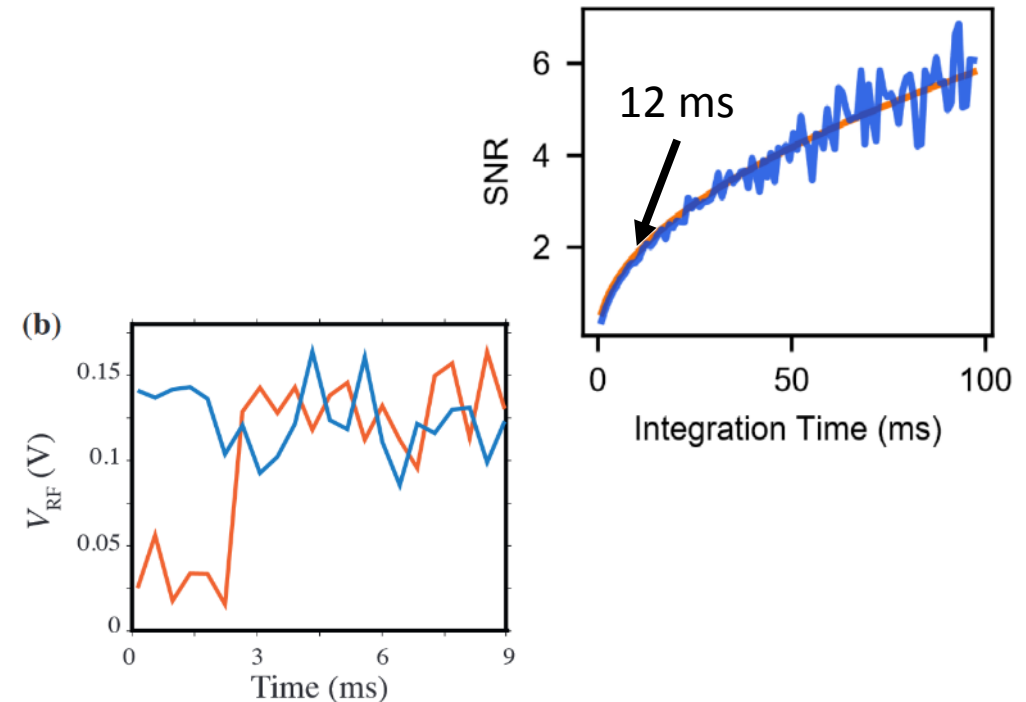
Q U A N T U M C O M P U T I N G

Initialization

Coherence Times

Motivation

- one of DiVincenzo's criteria: scalable physical system with well defined qubits
- readout for every single qubit has to be provided
 - QPC and SET: placed nearby and need additional gates
 - superconducting resonators (cQED): large footprint
- **gate based readout:** use what you already have
 - compact and simple
- single shot readout has been achieved in 2018
 - P. Pakkiam *et al.*, PRX **8**, 041032 (2018)
 - A. West *et al.*, arXiv:1809.01864v2
 - M. Urdampilleta *et al.*, arXiv:1809.04584 (2018)
- fast readout on μs scale (with low Q, lumped element resonator)
 - D. de Jong *et al.*, arXiv:1812.08609



Gate Reflectometry

- reflection of an electromagnetic wave depends on change of impedance

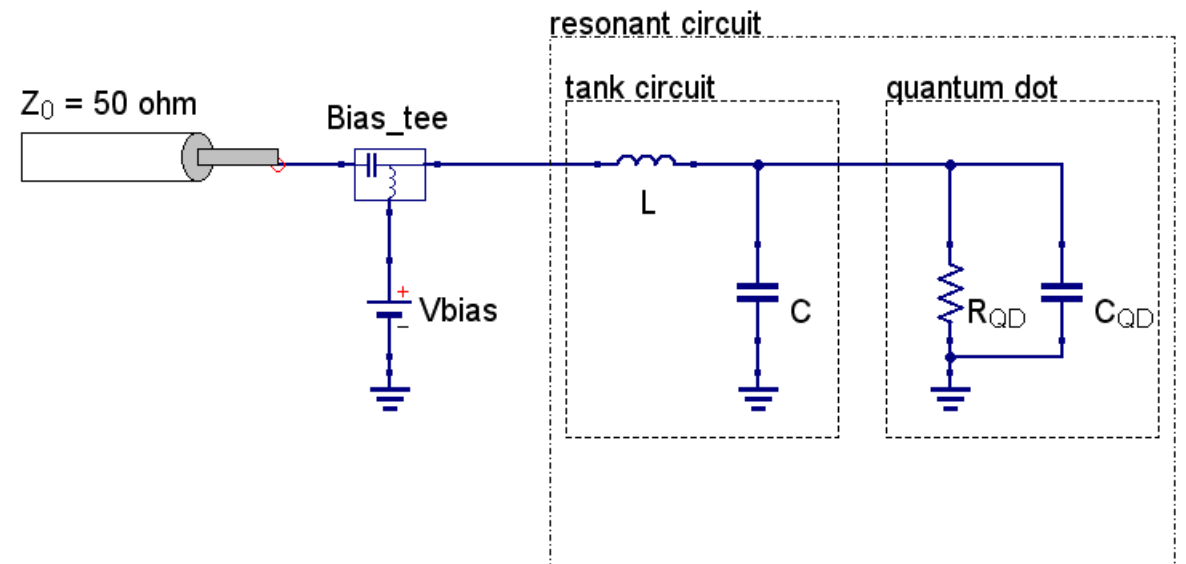
$$A_{\text{refl}} = A_{\text{in}} \cdot \Gamma = A_{\text{in}} \cdot \frac{Z - Z_0}{Z + Z_0}$$

- match large impedance of quantum device to 50 Ω impedance by using a **tank circuit**

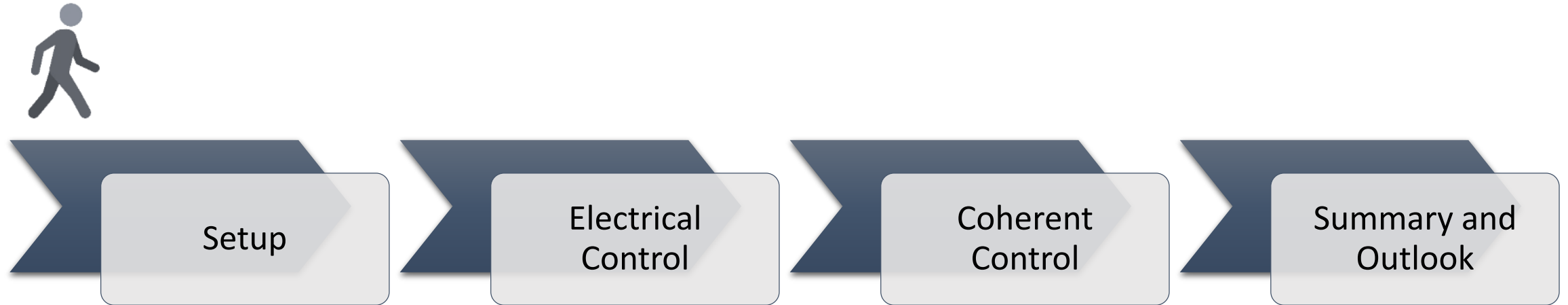
$$f_0 = \frac{1}{2\pi\sqrt{LC}}$$

- sensitive to change of quantum capacity
- detect change in amplitude and phase

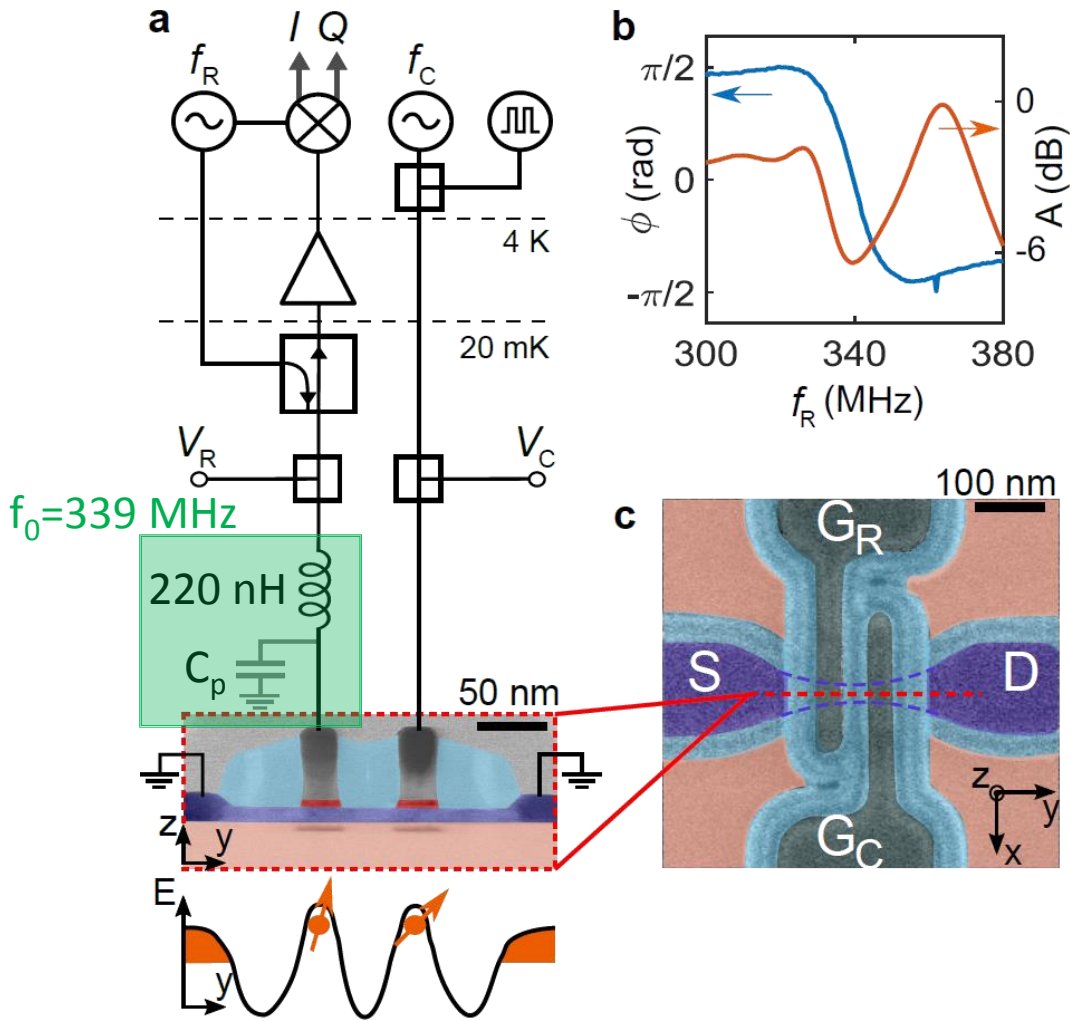
$$\Delta\phi \approx -\pi Q \frac{C_q}{C_p}$$



[1] Blog of Bruno K ung, Z rich Instruments,
<https://www.zhinst.com/blogs/brunok/rf-reflectometry-quantum-dots/>

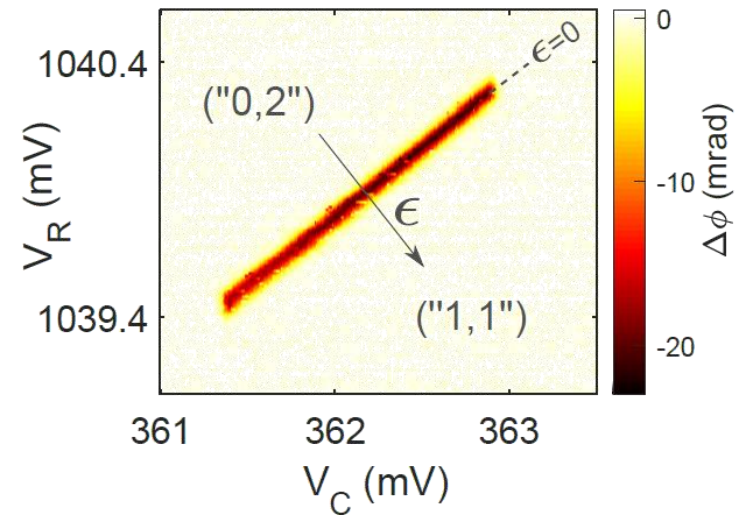


The Setup



- p-type Si transistor (300 mm SOI wafer, CMOS)
- quality factor ~ 18
- phase response upon impedance change:

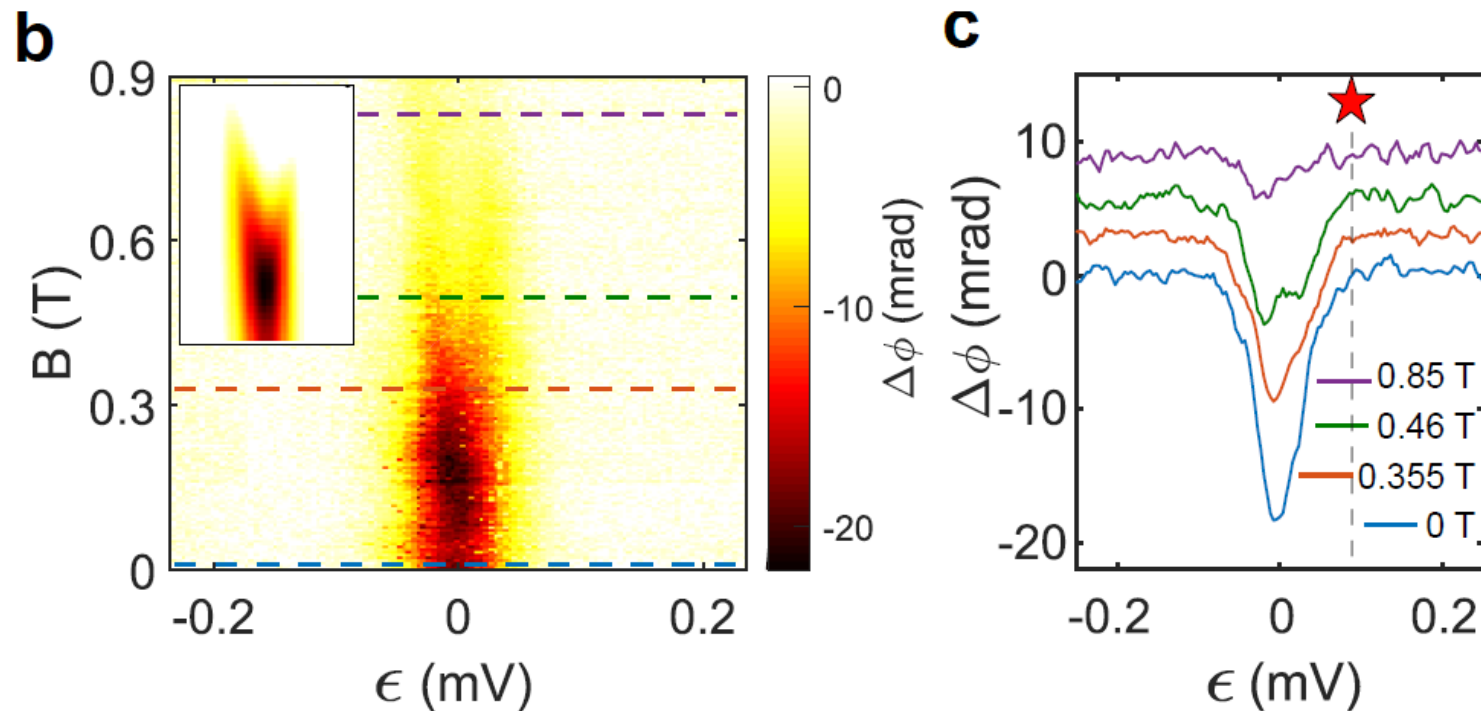
$$C_Q = -\alpha^2 \left(\frac{\partial^2 E_{\pm}}{\partial \epsilon^2} \right) \quad \alpha \simeq 0.58 \text{ eV/V}$$



[1] A. Crippa *et al.*, arXiv:1811.04414v1

Energy Spectrum

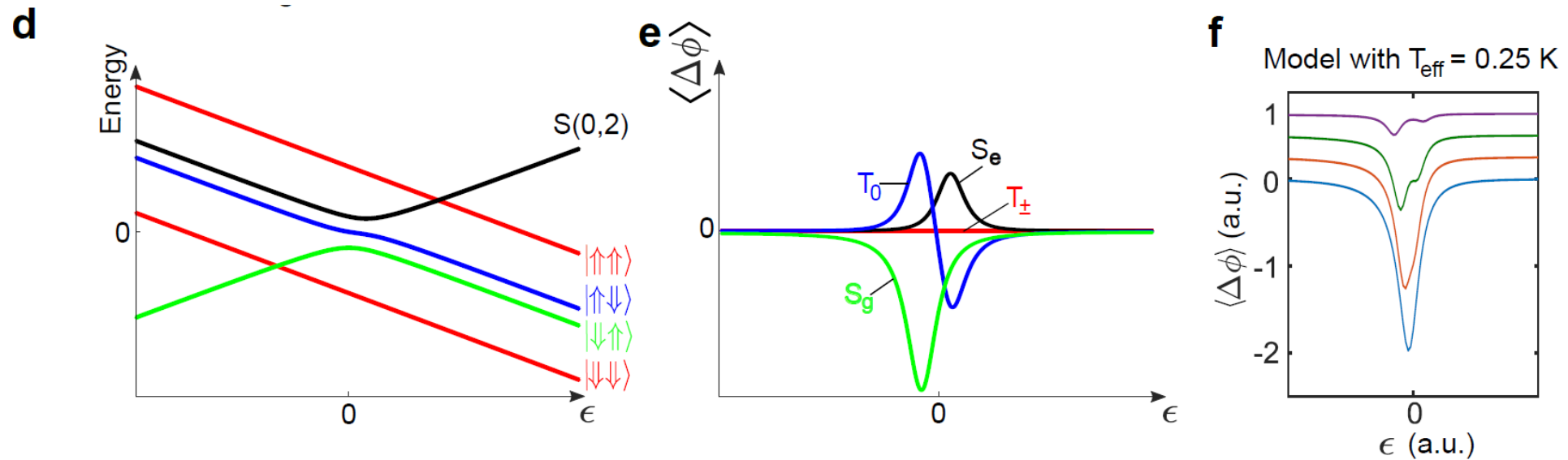
- not in the single hole regime
- determine charge parity from B-field dependence of interdot transition



[1] A. Crippa *et al.*, arXiv:1811.04414v1

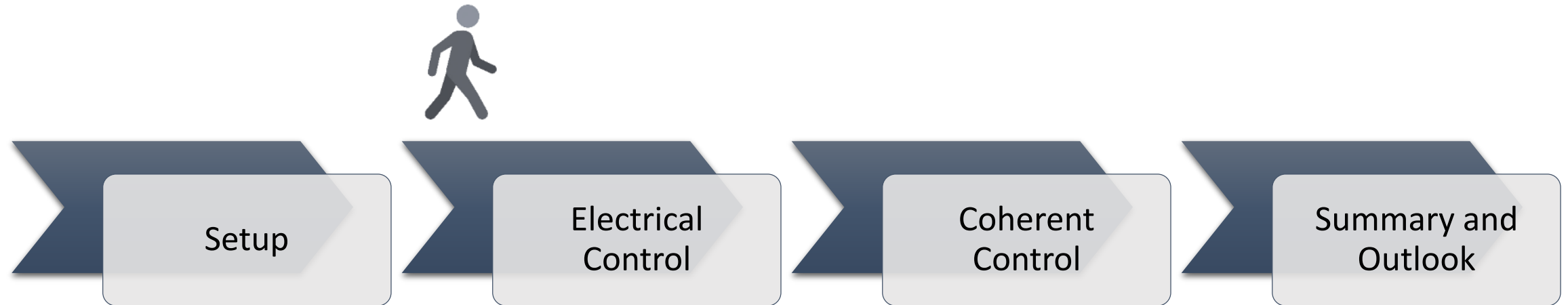
Energy Spectrum

- singlet-triplet like energy spectrum
- g-factor difference in left and right dot splits the states at positive detuning
- T_- and T_+ do not yield a phase response, because the state is linear in ϵ

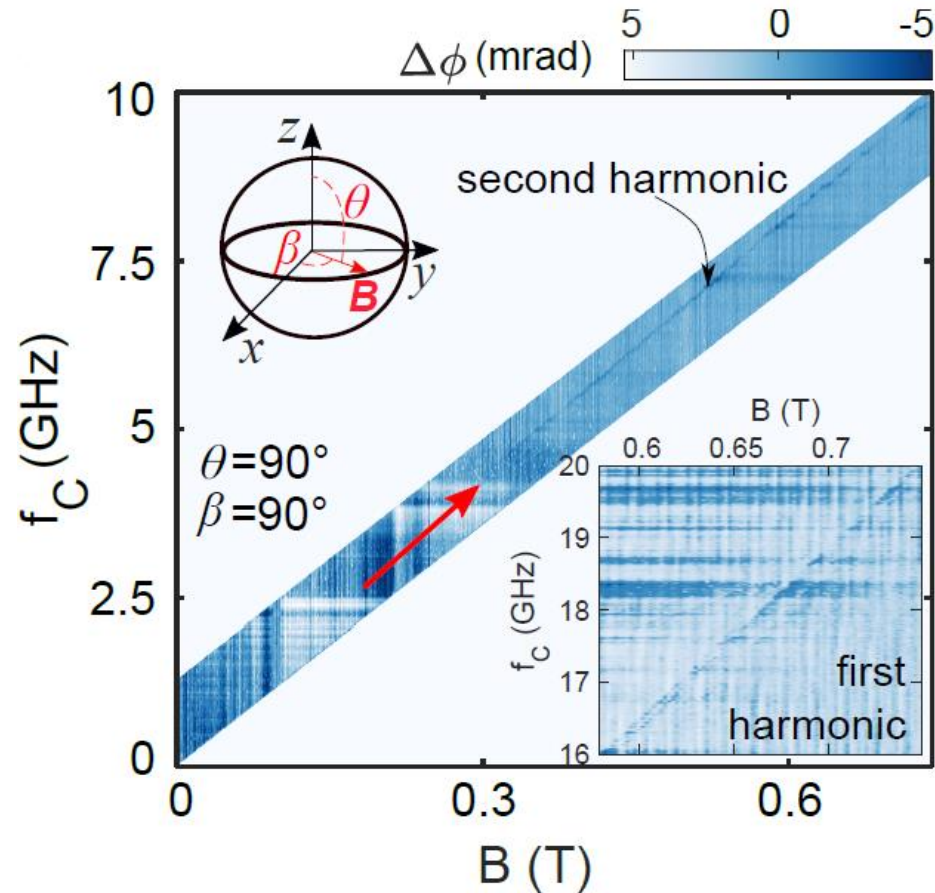


[1] A. Crippa *et al.*, arXiv:1811.04414v1

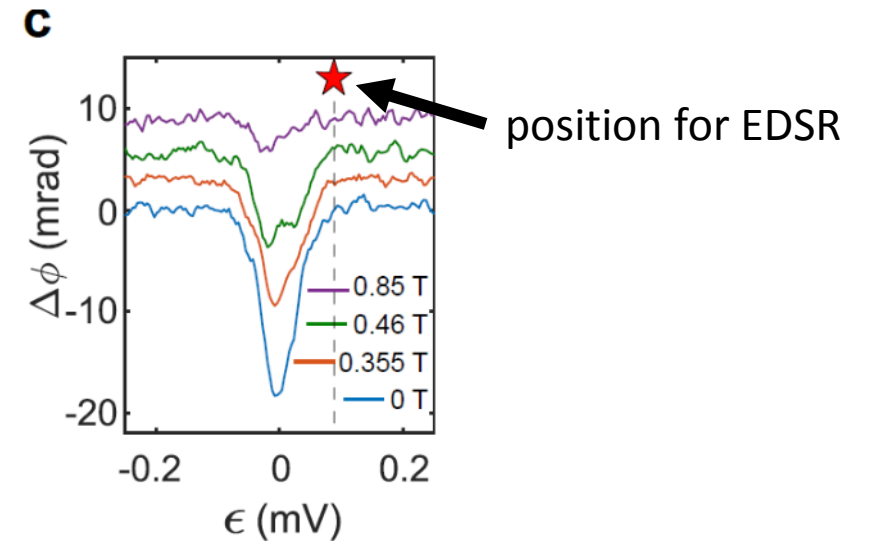
Outline



Electrical Control - EDSR

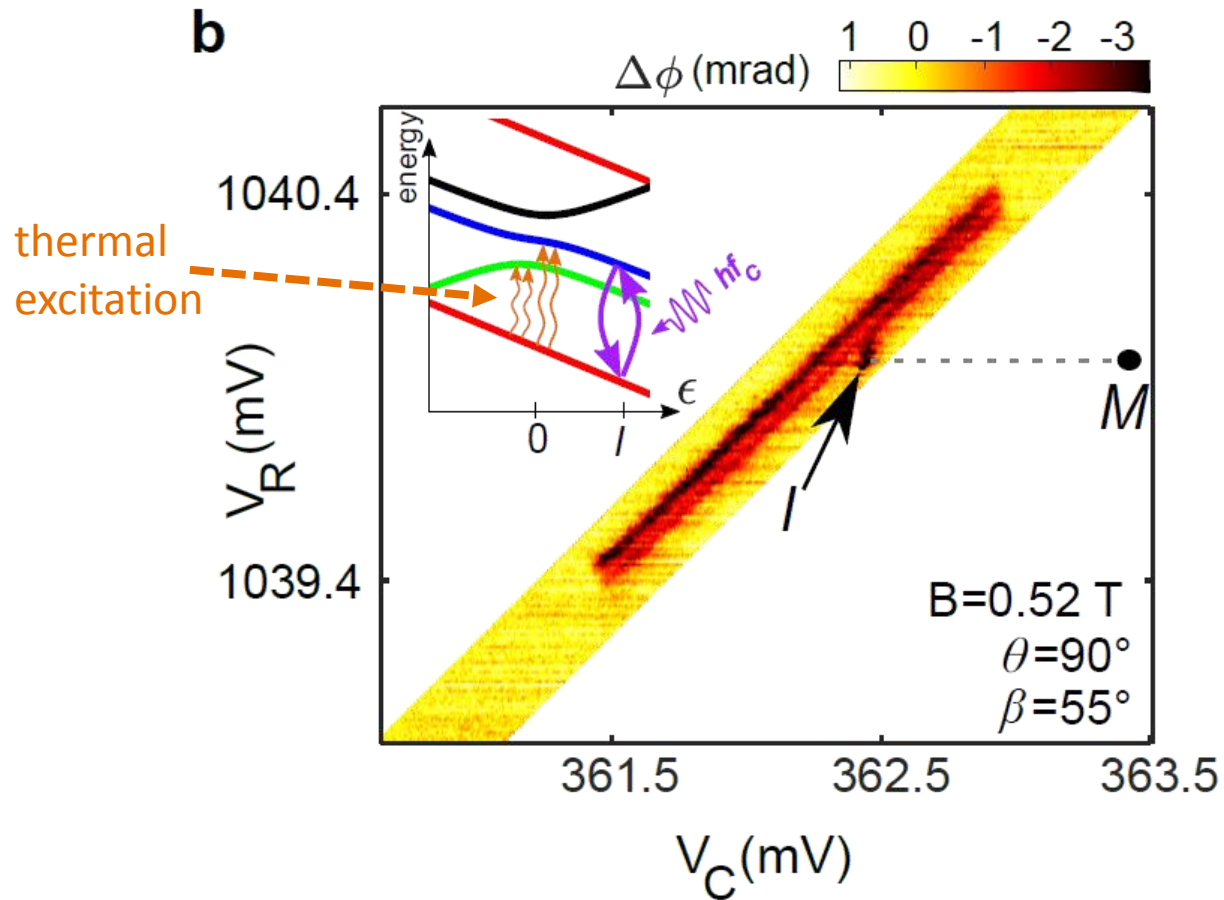


- matching condition: photon energy equals Zeeman splitting of spin states
- B parallel to nanowire
- second harmonic: $g=1.735$

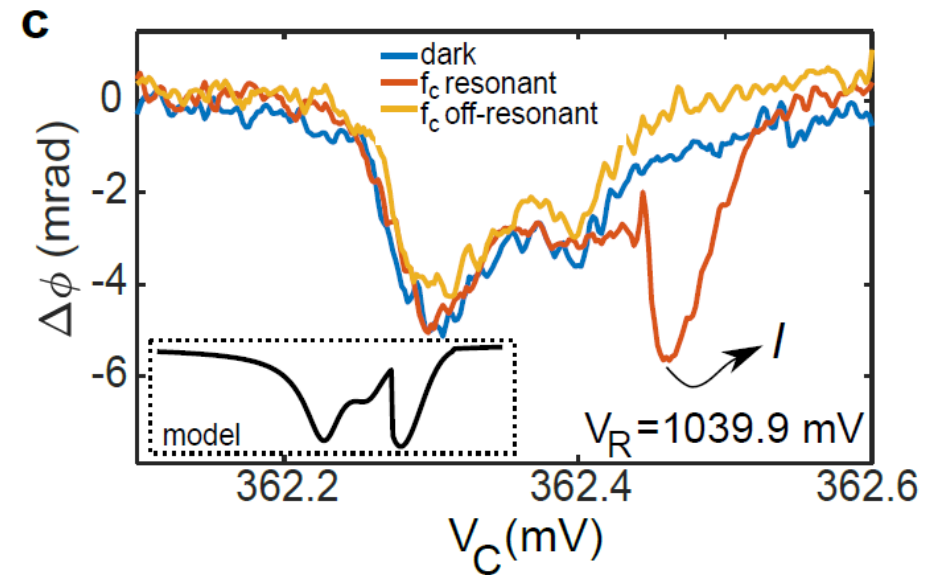


[1] A. Crippa *et al.*, arXiv:1811.04414v1

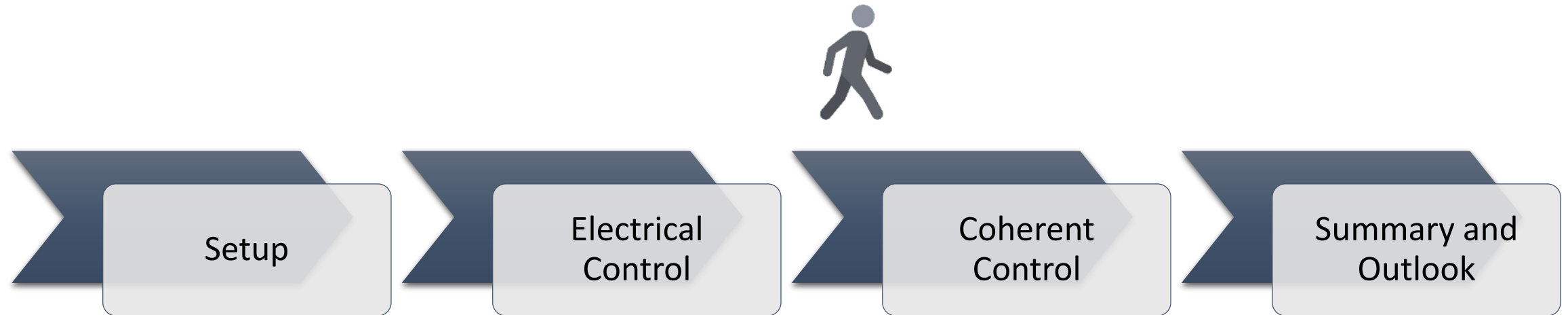
Resolve Single Spin Transitions



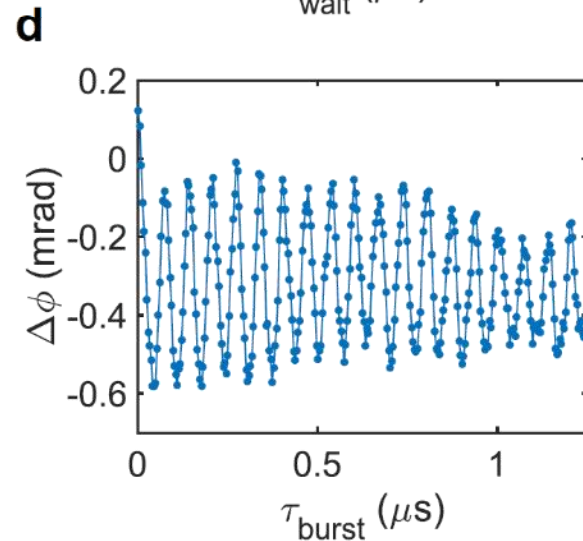
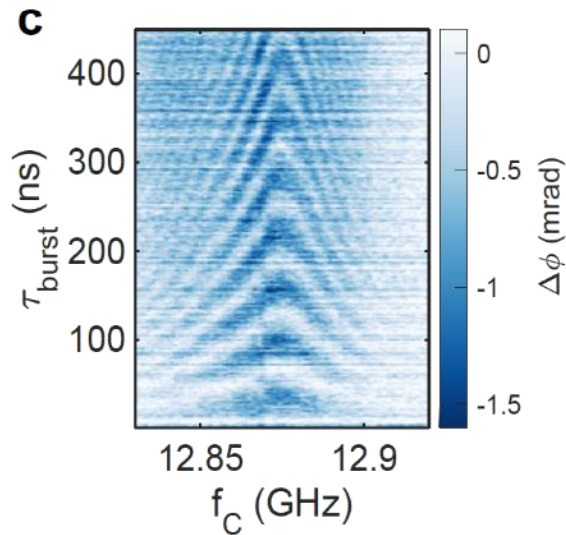
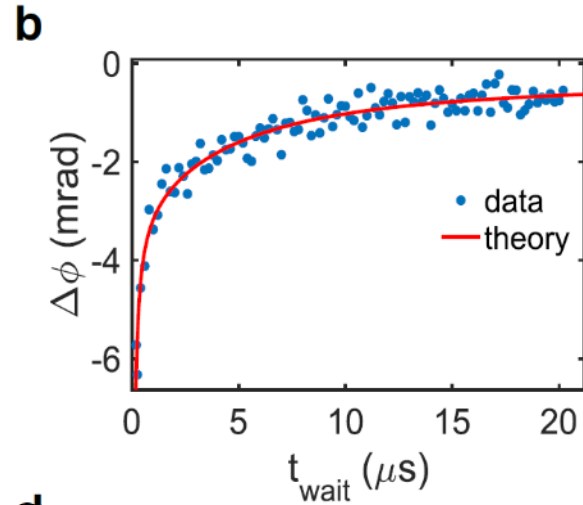
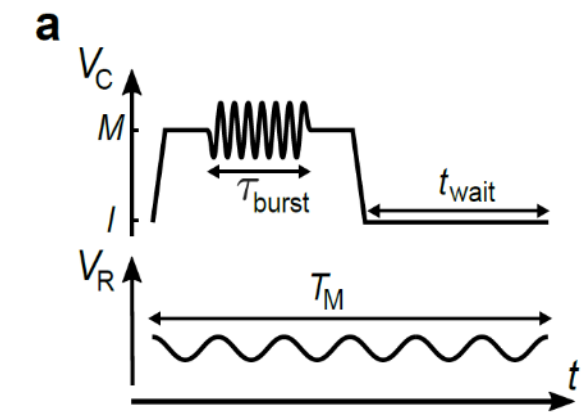
- phase signal is very distinct due to g-factor variation with gate voltages
- on resonance a peak is visible
 - indicates T_0 population driven by EDSR



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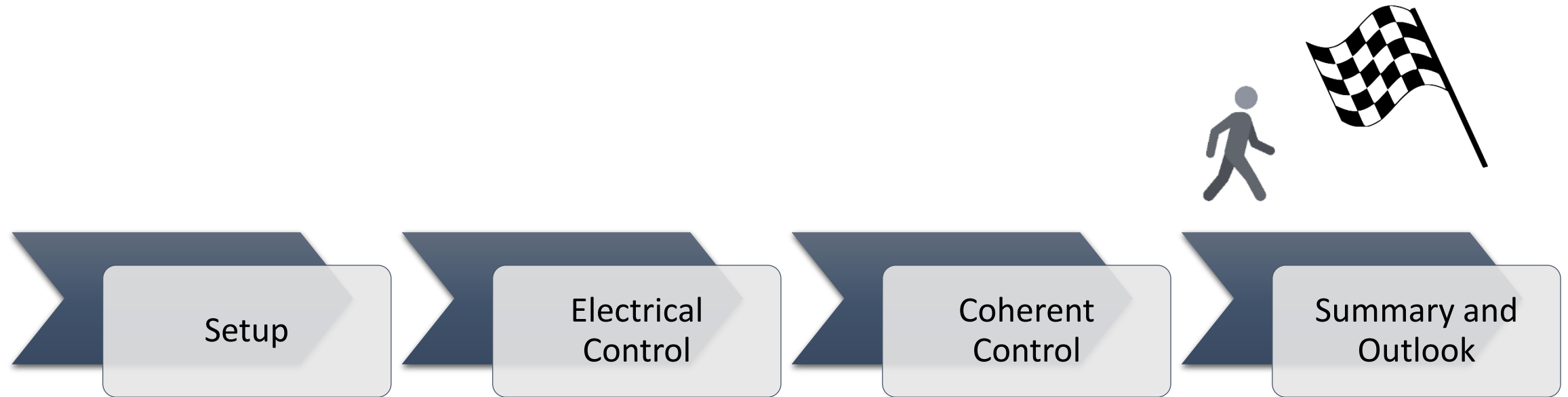
Coherent Spin Control



- spin qubit protocol:
 - initialize at point I , manipulate in $(1,1)$ region at point M
- τ_{Burst} drives transitions $|\uparrow\uparrow\rangle \leftrightarrow |\uparrow\downarrow\rangle$
- $T_1 = 2.7 \pm 0.7 \mu\text{s}$
- $f_{\text{Rabi}} = 15 \text{ MHz}$

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Outline



Summary and Outlook

- Qubit **operation** and **readout** with RF signals
- resolve
 - energy spectrum
 - single spin transitions
- coherent control of spin transitions
 - EDSR
 - Rabi oscillations
- study anisotropy of T_1
- improve T_1 by reducing backaction of amplifier

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